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## Thormal Characteristics

Symbol	Parameter	FCPF11N60F	Unit
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	3.5	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient, Max.	62.5	°C/W

1

mermai	Characteristics
0	

Symbol	Parameter			FCPF11N60F	Unit				
V <sub>DSS</sub>	Drain to Source Voltage	3		Prain to Source Voltage		in to Source Voltage 600		600	V
ID	Drain Current	- Continuous (T <sub>C</sub> = 25 <sup>o</sup> C)	- Continuous (T <sub>C</sub> = 25 <sup>o</sup> C)						
	Drain Current	- Continuous ( $T_C = 100^{\circ}C$ )		7*	Α				
I <sub>DM</sub>	Drain Current	- Pulsed	(Note 1)	33*	A				
V <sub>GSS</sub>	Gate to Source Voltage			±30	V				
E <sub>AS</sub>	Single Pulsed Avalanche Energy		(Note 2)	340	mJ				
I <sub>AR</sub>	Avalanche Current		(Note 1)	11	A				
E <sub>AR</sub>	Repetitive Avalanche Energy		(Note 1)	12.5	mJ				
dv/dt	Peak Diode Recovery dv/dt		(Note 3)	4.5	V/ns				
		(T <sub>C</sub> = 25 <sup>o</sup> C)		36	W				
P <sub>D</sub>	Power Dissipation	- Derate Above 25°C		0.29	W/ºC				
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range			-55 to +150	°C				
т.	Maximum Lead Temperature for Soldering,			300	°C				
ΤL	1/8" from Case for 5 Sec	onds		300	C				

TO-220F

### Description

SuperFET<sup>®</sup> MOSFET is Fairchild Semiconductor's first generation of high voltage super-junction (SJ) MOSFET family that is utilizing charge balance technology for outstanding low onresistance and lower gate charge performance. This technology is tailored to minimize conduction loss, provide superior switching performance, dv/dt rate and higher avalanche energy. Consequently, SuperFET MOSFET is very suitable for the switching power applications such as PFC, server/telecom power, FPD TV power, ATX power and industrial power applications. Super-FET FRFET® MOSFET's optimized body diode reverse recovery performance can remove additional component and improve system reliability.



# N-Channel SuperFET<sup>®</sup> FRFET<sup>®</sup> MOSFET

600 V, 11 A, 380 mΩ

#### Features

- 600 V @ T<sub>J</sub> = 150°C
- Typ. R<sub>DS(on)</sub> = 320 mΩ
- Fast Recovery Type (t<sub>rr</sub> = 120 ns)
- Ultra Low Gate Charge (Typ. Q<sub>g</sub> = 40 nC)
- Low Effective Output Capacitance (Typ. C<sub>oss(eff.)</sub> = 95 pF)
- 100% Avalanche Tested
- · RoHS compliant

### Applications

LCD/LED/PDP TV

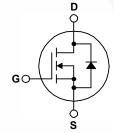
Lighting

 Solar Inverter · AC-DC Power Supply

MOSFET Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted.



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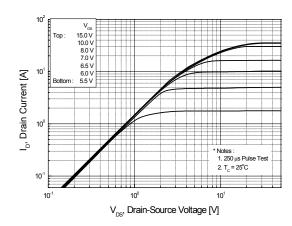
November 2013

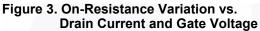
Device Mid	rking	Device	Packa	ge	Reel Size	Тар	e Width		Quantit	у
FCPF11N	160F	FCPF11N60F	TO-220	0F	-		-		50	
Electrica	l Char	acteristics T <sub>c</sub> =	= 25°C unless	otherwi	se noted					
Symbol		Parameter			Test Conditions		Min.	Тур.	Max.	Unit
Off Charac	teristic	s								
		•		Vec =	$0 V = 250 \mu A T_{o}$	= 25°C	600		_	V
BV <sub>DSS</sub>	Drain to	Source Breakdown V	/oltage	$V_{GS} = 0 V, I_D = 250 \mu A, T_C = 25^{\circ}C$ $V_{GS} = 0 V, I_D = 250 \mu A, T_C = 150^{\circ}C$		-	650	_	V	
ΔΒV <sub>DSS</sub> / ΔΤ <sub>J</sub>	Breakdo	own Voltage Temperat	ture		50 μA, Referenced to		-	0.6	-	V/°C
BV <sub>DS</sub>		ource Avalanche Brea	akdown	V <sub>GS</sub> =	0 V, I <sub>D</sub> = 11 A		-	700	-	V
				Vpe =	600 V, V <sub>GS</sub> = 0 V		-	-	1	
IDSS	Zero Ga	ate Voltage Drain Curr	ent		$480 \text{ V}, \text{ T}_{\text{C}} = 125^{\circ}\text{C}$		-	-	10	μA
I <sub>GSS</sub>	Gate to	Body Leakage Currer	nt	-	±30 V, V <sub>DS</sub> = 0 V		-	-	±100	nA
On Charac				•63						
V <sub>GS(th)</sub>	-1	reshold Voltage		V <sub>GS</sub> = V <sub>DS</sub> , I <sub>D</sub> = 250 μA			3.0	_	5.0	V
R <sub>DS(on)</sub>		rain to Source On Re	sistance		10 V, I <sub>D</sub> = 5.5 A		-	0.32	0.38	Ω
9FS		d Transconductance		$V_{\rm DS} = 40 \text{ V}, \text{ I}_{\rm D} = 5.5 \text{ A}$		-	6	-	S	
Dynamic C				00						-
C <sub>iss</sub>		apacitance					-	1148	1490	pF
C <sub>oss</sub>		Capacitance		V <sub>DS</sub> =	25 V, $V_{GS}$ = 0 V,	-	-	671	870	pF
O <sub>oss</sub> C <sub>rss</sub>	-	e Transfer Capacitanc	۵	f = 1.0 MHz		_	63	82	pF	
C <sub>oss</sub>	· · · · · · · · · · · · · · · · · · ·		V <sub>PO</sub> =	/ <sub>DS</sub> = 480 V, V <sub>GS</sub> = 0 V, f = 1.0 MHz		-	35		pF	
C <sub>oss(eff.)</sub>	Effective Output Capacitance			$V_{\rm DS} = 0 \text{ V to } 400 \text{ V}, \text{ V}_{\rm GS} = 0 \text{ V}$		-	95	-	pF	
Q <sub>g(tot)</sub>		ate Charge at 10V				•••	-	40	52	nC
$Q_{gs}$		Source Gate Charge		V <sub>DS</sub> = 480 V, I <sub>D</sub> = 11 A, V <sub>GS</sub> = 10 V (Note 4)		-	7.2	-	nC	
∽gs Q <sub>gd</sub>		Drain "Miller" Charge				-	21	-	nC	
Switching										110
_		Delay Time					- 1	34	80	ns
t <sub>d(on)</sub> t		Rise Time		Vpp =	300 V, I <sub>D</sub> = 11 A,	÷		98	205	ns
t <sub>r</sub>		f Delay Time		$R_{G} = 25 \Omega$			119	250	ns	
ld(off) te		Fall Time				_	56	120	ns	
t <sub>f</sub>						(Note 4)		50	120	113
		de Characteristic		I.а. <b>Г</b> .а.т. на	and Ourmant				44	٨
l <sub>S</sub>		m Continuous Drain to					-	-	11	A
I <sub>SM</sub>	Maximum Pulsed Drain to Source Diode Drain to Source Diode Forward Voltage					-	-	33 1.4	A	
		Recovery Time				-	- 120	-		
V <sub>SD</sub>	Reverse			V <sub>GS</sub> = 0 V, I <sub>SD</sub> = 11 A, dI <sub>F</sub> /dt = 100 A/μs		-	-	0.8	-	ns µC
v <sub>SD</sub> frr Q <sub>rr</sub>	Dovorso	Recovery Charge								

## Typical Performance Characteristics

#### Figure 1. On-Region Characteristics

#### Figure 2. Transfer Characteristics





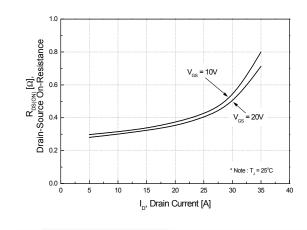
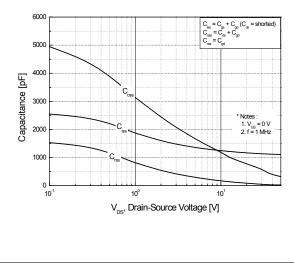
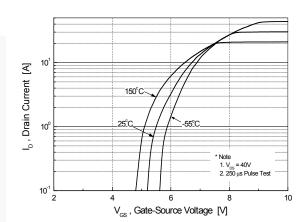


Figure 5. Capacitance Characteristics







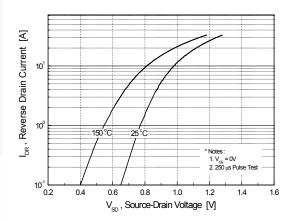
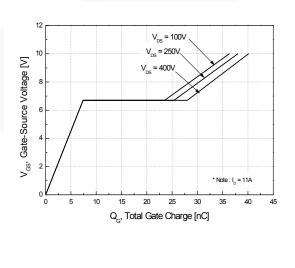
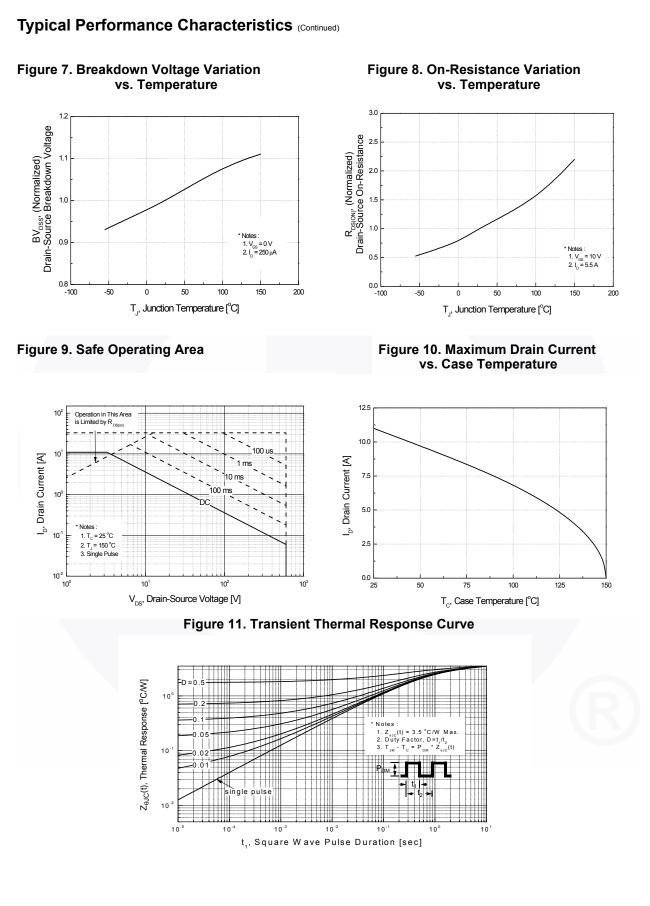
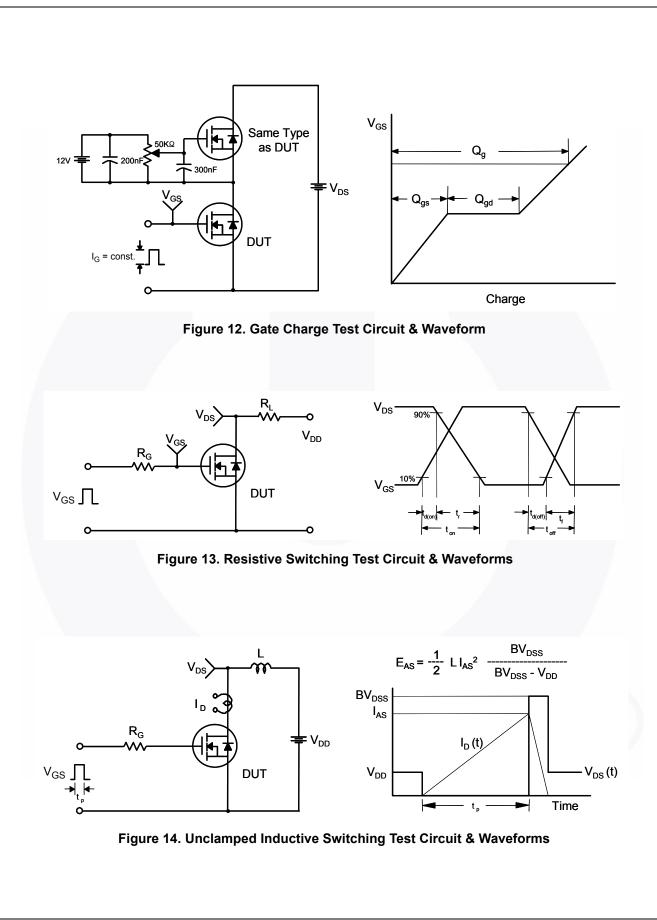
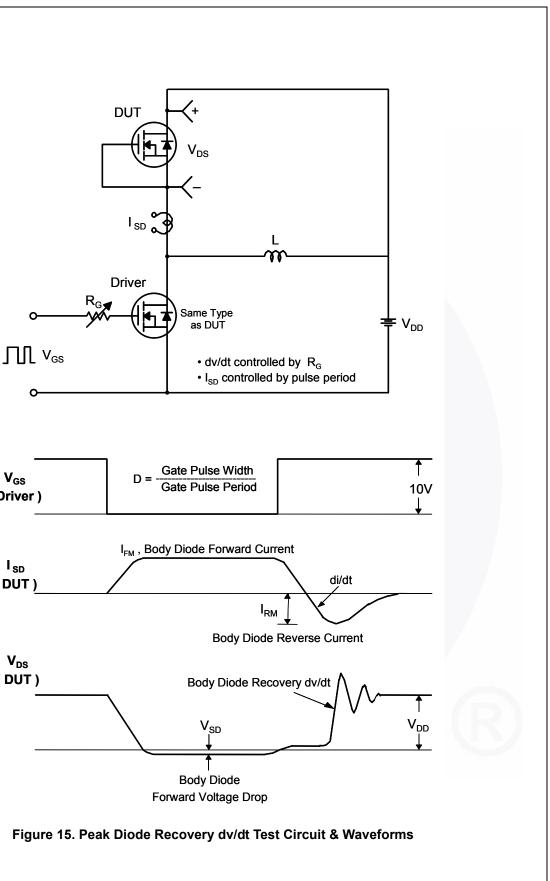


Figure 6. Gate Charge Characteristics









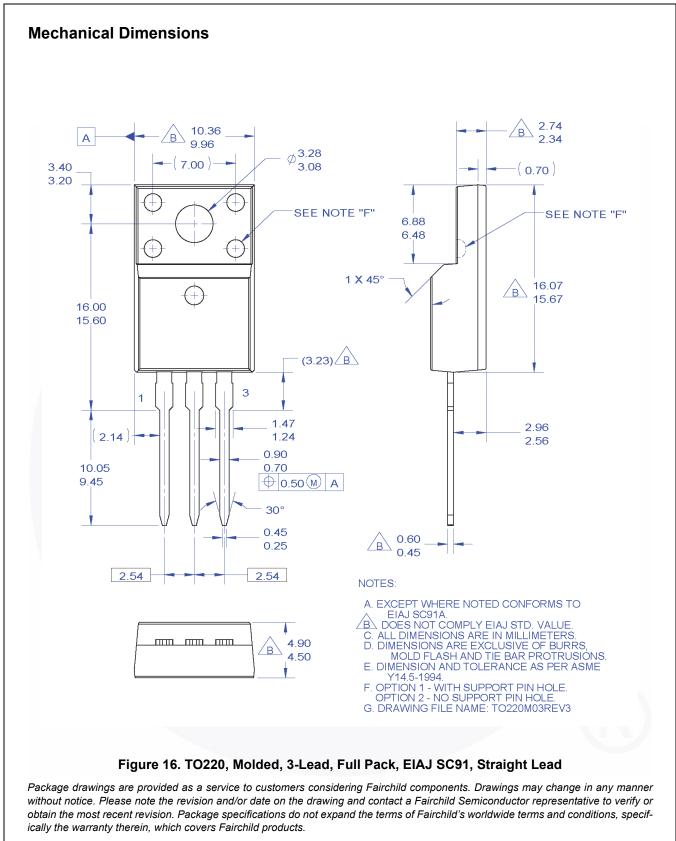
V<sub>GS</sub>

(Driver)

I <sub>SD</sub>

(DUT)

V<sub>DS</sub> (DUT)



Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings:

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FCPF11N60F — N-Channel SuperFET<sup>®</sup> FRFET<sup>®</sup> MOSFET



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